

TECHNICAL DATA Datasheet 4118, Rev. C

Three-Phase MOSFET BRIDGE, With Gate Driver and Optical Isolation

DESCRIPTION: A 100 VOLT, 80 AMP, THREE PHASE MOSFET BRIDGE

ELECTRICAL CHARACTERISTICS PER MOSFET DEVICE

(Ti=25°C UNLESS OTHERWISE SPECIFIED)

ELECTRICAL CHARACTERISTICS PER MOSFET DEVICE			J=25 C UNLESS OTHERWISE SPECIFIED)			
SYMBOL	MIN	TYP	MAX	UNIT		
MOSFET SPECIFICATIONS						
BV _{DSS}	100	-	-	V		
I _D	-	-	80	Α		
			70			
I _{DM}	-	-	200	А		
V _{GS}	-	-	+/-20	V		
I _{GSS}	-	-	+/- 200	nA		
I _{CSS}	-	-				
			1	mA		
			3	mA		
R _{DSon}	-	0.009	0.012	V		
		0.018	-			
R _{0JC}	-	-	0.65	°C/W		
T _{jmax}	-40	-	150	°C		
T _{jmax}	-55	-	150	°C		
	SYMBOL BV _{DSS} I _D I _{DM} V _{GS} I _{GSS} I _{CSS} R _{DSon} R _{e,JC} T _{jmax}	SYMBOL MIN BV _{DSS} 100 I _D - I _{DM} - V _{GS} - I _{GSS} - I _{CSS} - R _{DSon} - R _{e,JC} - T _{jmax} -40	SYMBOL MIN TYP BV _{DSS} 100 - I _D - - I _{DM} - - V _{GS} - - I _{GSS} - - I _{CSS} - - R _{DSon} - 0.009 0.018 - - T _{jmax} -40 -	SYMBOL MIN TYP MAX BV _{DSS} 100 - - I _D - - 80 70 - 200 V _{GS} - - +/-20 I _{GSS} - - +/-200 I _{CSS} - - 1 R _{DSon} - 0.009 0.012 0.018 - - 0.65 T _{jmax} -40 - 150		

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Over-Temperature Shutdown						
Over-Temperature Shutdown	Tsd	105	110	115	°C	
Over-Temperature Output	Tso		10		10mV/°C	
Over-Temperature Shutdown Hysteresis			20		°C	

DIODES CHARACTERISTICS					
Continuous Source Current, T _C = 90 ^o C	Is	-	-	70	А
Diode Forward Voltage, $I_S = 60A$, $T_j = 25$ $^{\circ}C$	V _{SD}	-		1.15	V
Diode Reverse Recovery Time (I_S =50A, V_{DD} =50V , di/dt=100 A/ μ s)	t _{rr}	-	70	-	nsec
Gate Driver					
Supply Voltage	VCC	10	15	20	V
Input On Current	HIN, LIN	2		5.0	mA
Opto-Isolator Logic High Input Threshold	I _{th}	-	1.6	-	mA
Input Reverse Breakdown Voltage	BV _{in}	5.0	-	-	V
Input Forward Voltage @ I _{in} = 5mA	V _F	-	1.5	1.7	V
Under Voltage Lockout	VCCUV	11.5	-	12.5	V
ITRIP Reference Voltage (1)	Itrip-ref	2.5	2.6	2.7	V
Input-to-Output Turn On Delay	t _{ond}	-	700	-	nsec
Output Turn On Rise Time	t _r	-	50	-	
Input-to-Output Turn Off Delay		-	750	-	
Output Turn Off Fall Time	t _{offd}	-	60	-	
@ VCC=50V, ID=50A, T _C = 25	t _f				
Input-Output Isolation Voltage	-	1500	-	-	V

⁽¹⁾ ITRIP Cycle-by cycle current limit is internally set to 43A peak. The set point can be lowered by connecting a resistor between Itrip-ref and Gnd. The set point can be increased by connecting a resistor between Itrip-ref and +5V ref

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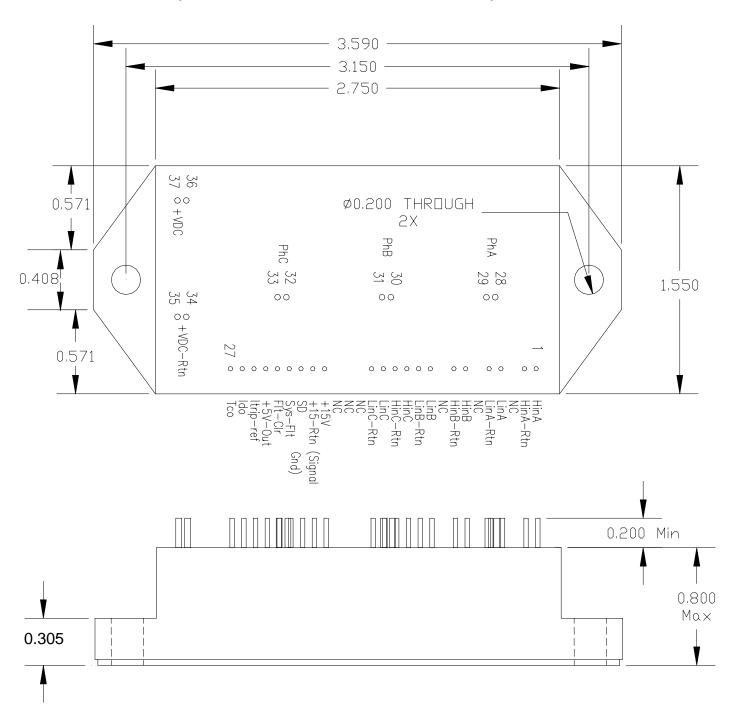
Pin Description

Pin Number	Function	Pin Number	Function		
1	Isolated Input for High-side MOSFET of Phase A	18	NC		
2	Return for Input at 1	19	+15V Input		
3	NC	20	+15V Rtn (Signal Ground) (3)		
4	Isolated Input for Low-side MOSFET of Phase A	21	SD ⁽³⁾		
5	Return for Input at 4	22	Fault Output (3)		
6	NC	23	Fault Clear Input (3)		
7	Isolated Input for High-side MOSFET of Phase B	24	+5V Output		
8	Return for Input at 7	25	Over-Current Trip Set Point (3)		
9	NC	26	DC Bus Current Output with Total Gain of 0.06 V/A		
10	Isolated Input for Low-side MOSFET of Phase B	27	Case Temperature Output with Gain of 0.010 V/°C		
11	Return for Input at 10	28 &29	Phase A Output		
12	Isolated Input for High-side MOSFET of Phase C	30 & 31	Phase B Output		
13	Return for Input at 12	32 & 33	Phase C Output		
14	Isolated Input for Low-side MOSFET of Phase C	34 & 35	DC Bus "+VDC Return"		
15	Return for Input at 14	36 & 37	DC Bus "+VDC" Input		
16	NC	Case	Isolated From All Terminals		
17	NC				

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Package Drawing Top View (All dimensions are in inches, tolerance is +/- 0.010") (Base Plate flatness is +/- 0.004" maximum)

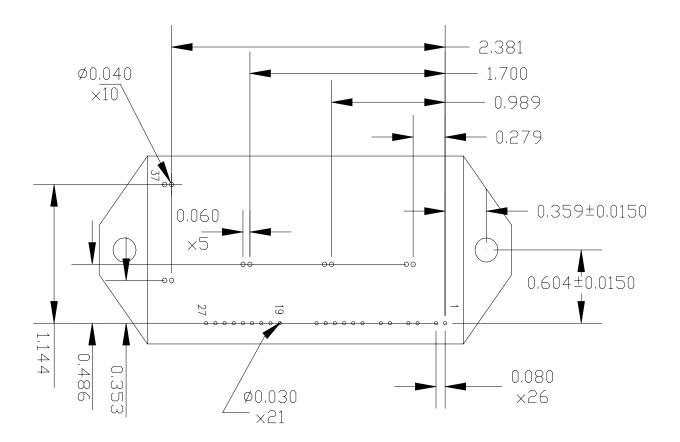


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Package Pin Locations (All dimensions are in inches; tolerance is +/- 0.005" except otherwise specified)



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Application Notes:

a- Shutdown Feature:

- 1- Pin 21, SD is a dual function input/output, active low input. It is internally pulled high. As a low input, it shuts down all MOSFETs regardless of the Hin and Lin signals.
- **2-** SD is also internally activated by the over-temperature shutdown, over-current limit, under-voltage shutdown, and desaturation protection.
- **3-** Over-temperature shutdown, and over-current limit are not latching features.
- **4-** Under-voltage shutdown is automatically reset once the VCC rises above the 12.1V threshold limit.
- **5-** Desaturation shutdown is a latching feature and internally reset.
- **6-** When any of the internal protection features are activated, SD is pulled down.
- **7-** SD can be used to shutdown all MOSFETs by an external command. An open collector switch shall be used to pull down SD externally.
- 8- Also, SD can be used as a fault condition output. Low output at SD indicates a fault situation.

b- Fault Output Feature:

- 1- Pin 22, Flt is a dual function pin. It is internally pulled high. If pulled down, it will freeze the status of all the six MOSFETs regardless of the Hin and Lin signals
- **2-** Pin 22 as an output reports desaturation protection activation. When desaturation protection is activated a low output for about 9 μsec is reported.
- 3- If any other protection feature is activated, it will not be reported by Pin 22.

c- Fault Clear Output:

- **1-** Pin 23, Flt-Clr is a fault clear input. It can be used to reset a latching fault condition, due to desaturation protection.
- **2-** Pin 23 is internally pulled down. A latching fault due to desaturation can be cleared by pulling high this input.
- **3-** An internal fault clear is activated after 100 μ sec delay. If desired to clear the fault earlier, this input can be used.

d- Signal Ground:

Pin 20, Signal Gnd is the signal ground for all signals at Pins 19 through 27. This ground is internally connected to the +VDC Rtn. **No external connection shall be established between Signal Gnd and +VDC Rtn.**

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